## EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	2449	p-channel MOS and first transistor	US-PGPUB; USPAT; USOCR; IBM_TDB	ADJ	ON	2007/12/09 20:29
S2	310	p-channel MOS same first transistor	US-PGPUB; USPAT; USOCR; IBM_TDB	ADJ	ON	2007/12/09 20:29
S3	9	p-channel MOS same first transistor and ESD	US-PGPUB; USPAT; USOCR; IBM_TDB	ADJ	ON	2007/12/09 20:30
<b>S</b> 4	1	(p-channel MOS) same (N-channel MOS) same (first transistor) SAME (second transistor) same (third transistor) same (fourth transistor) and ESD	US-PGPUB; USPAT; USOCR; IBM_TDB	ADJ	ON	2007/12/09 20:36
\$5	116	(first transistor) SAME (second transistor) same (third transistor) same (fourth transistor) and ESD	US-PGPUB; USPAT; USOCR; IBM_TDB	ADJ	ON	2007/12/09 20:36

S6	4	(first transistor) SAME (second transistor) same (third transistor) same (fourth transistor) and ESD and (N- type MOSFETS) and (P-type MOSFETS)	US-PGPUB; USPAT; USOCR; IBM_TDB	ADJ	ON	2007/12/09 20:40
S7	45	(first transistor) SAME (P-type MOSFETS)	US-PGPUB; USPAT; USOCR; IBM_TDB	ADJ	ON	2007/12/09 20:43
S8	1	(first transistor) SAME (P-type MOSFETS) AND ESD	US-PGPUB; USPAT; USOCR; IBM_TDB	ADJ	ON	2007/12/09 20:43
S9	17	(first transistor) AND (P-type MOSFETS) AND ESD	US-PGPUB; USPAT; USOCR; IBM_TDB	ADJ	ON	2007/12/09 20:44
S10	1	(first transistor) SAME (P-type MOSFETS) AND ESD	US-PGPUB; USPAT; USOCR; IBM_TDB	ADJ	ON	2007/12/09 20:46
S11	45	(first transistor) SAME (P-type MOSFETS)	US-PGPUB; USPAT; USOCR; IBM_TDB	ADJ	ON	2007/12/09 20:46
S12	8	(first transistor) SAME (P-type MOSFETS) AND protection AND circuit	US-PGPUB; USPAT; USOCR; IBM_TDB	ADJ	ON	2007/12/09 20:48
S13	7	(first transistor) near5 (P-type MOSFETS) AND protection AND circuit	US-PGPUB; USPAT; USOCR; IBM_TDB	ADJ	ON	2007/12/09 20:51
S14	0	(first transistor) near5 (P-type MOSFETS) AND ESD	US-PGPUB; USPAT; USOCR; IBM_TDB	ADJ	ON	2007/12/09 20:55

S15	0	(first transistor) near10 (P-type MOSFETS) AND ESD	US-PGPUB; USPAT; USOCR; IBM_TDB	ADJ	ON	2007/12/09 20:55
S16	0	(first transistor) near5 (P-type MOSFETS) AND ESD	US-PGPUB; USPAT; USOCR; IBM_TDB	ADJ	ON	2007/12/09 20:56
S17	0	(first transistor) near2 (P-type MOSFETS) AND ESD	US-PGPUB; USPAT; USOCR; IBM_TDB	ADJ	ON	2007/12/09 20:56
S18	0	(first transistor) WITH (P-type MOSFETS) AND ESD	US-PGPUB; USPAT; USOCR; IBM_TDB	ADJ	ON	2007/12/09 20:56
S19	1	(first transistor) SAME (P-type MOSFETS) AND ESD	US-PGPUB; USPAT; USOCR; IBM_TDB	ADJ	ON	2007/12/09 20:56
S20	45	(first transistor) SAME (P-type MOSFETS)	US-PGPUB; USPAT; USOCR; IBM_TDB	ADJ	ON	2007/12/09 20:57
\$21	98	(first transistor) SAME (P-type MOSFETS or P- MOS)	US-PGPUB; USPAT; USOCR; IBM_TDB	ADJ	ON	2007/12/09 20:59
S22	3	5	US-PGPUB; USPAT; USOCR; IBM_TDB	ADJ	ON	2007/12/09 20:59
S23	53	(first transistor) SAME (P-type MOSFETS or P- MOS or P- CHANNEL) AND ESD	US-PGPUB; USPAT; USOCR; IBM_TDB	ADJ	ON	2007/12/09 21:04

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